



 MODEL NUMBER:
 20 Watt Low Power FF CW Amplifier

 FEATURES
 Image: Comparison of the second second

DESCRIPTION:

For test and measurement applications that require RF power of 20 Watts, CPT offers the 6900K Series power amplifier. For testing on antenna ranges, in EMC chambers, or an a test bench, CPI provides equipment built with quality and reliability that you can trust.

The 6900K series amplifiers are constructed with proven reliable all-metal-ceramic traveling wave tubes (TWTs), which are renowned for their high power and wideband capabilities. These TWTs have a wide range of applications and are readily available, resulting in CP's ability to offer additional tubes in a timely manner. The power supply for the 6900K series has a calculated MTBF of more than 41,000 hours. Combined with CPI TWTs, the 6900K series amplifier provides the industry standard for dependability.

The 6900K series TWT amplifier has a full line of standardized options including remote control, input and output isolators, and harmonic filters. For ATE applications, IEEE 488 bus controllable umplifiers* are available, with internal GPIB cards or external modules. More than a thousand CPI 6900K series amplifiers are used throughout the world, performing over a wide range of specifications, in a variety of environmental and operating conditions.

CPI 6900K series TWT amplifiers are manufactured with the same quality as all CPI amplifiers and are backed by CPI's worldwide 24-hour customer support network that includes 9 regional factory service centers. Quality, reliability, and product support are integral parts of your CPI power amplifier.

Model #	Power (Watts)	Freq (GHz)	Gain (dB)	O/P Conn
VZL-6941K1	20	1-2	35	Ν
VZS-6951K1	20	2-4	35	N
VZC-6961K1	20	4-8	35	N
VZX-6981K1	20	8-12.4	40	N
VZU-6991K1	20	12.4-18	40	N
VIM-6991K3	20	8-18	40	Ν

SELECTION GUIDE

For special frequency ranges and options, please contact the factory.

*For models with integral IEEE 488 capability, please refer to publication MKT 45, 6900K7 Series

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SPECIFICATIONS

Frequency Range	1.0 to 18 GHz (see Selection Guide)
Rated Output Power	20 Watls CW. Saturated output power may exceed rated power by 6 dB or more near band center. Output power is reduced by the insertion loss of all microwave options added at the output. (Options C, D, E, J).
Small Signal Gain	35 to 40 dB (see Selection Guide). Typically 10 to 20 dB higher near band center. Gain at Saturated Power is typically 5 dB less than small signal gain. Gain Is reduced by ihe insertion loss of all microwave options.
Gain Slability	0.25 dB/day at constant drive and temperature.
Gain Variation	10 dB peak-to-peak (typical), except M-Band 15 dB (typical)
Impedance	50 Ohms nominal
VSWR Input: Output: Load	2.0:1 typical2.0:1 typical1.3:1 max. for full spec compliance, 2.0:1 max. for no damage.Any value without damage if Option D is included.
Noise & Spurious	-50 dBc typical excluding harmonics and residual modulation
Residual AM	-40 dBc
Residual FM	Less than 4 kHz peak-to-peak in any 5 MHz band
AM/PM Conversion	2.5/dB typical at 6 dB below rated output
Noise Figure	35 dB max.
Harmonic Content	-3 dBc at lower band edge decreasing to -15 dBc (typical) at upper band edge without optional harmonic filter

METERS, MONITORS, CONTROLS & INDICATORS

Meters	Helix Current, Filament Elapsed Time (Option H)		
Monitors	Output Sample Port (Option E)		
Controls	 Mains Power ON/OFF High Voltage ON/OFF and/or Fault Reset, Local/Remote (Option G) RF Attenuator (Option B) 		
Indicators	 Mains Power ON Operate/Standby Summary Fault Current Fault (TWT Helix) 		

METERS, MONITORS, CONTROLS & INDICATORS

Ambient Temperature	0 to +50°C
Relative Humidity	95% non-condensing
Altitude	6,000 feet max.
Shock & Vibration	As normally encountered in a protected engineering laboratory environment
Cooling	Forced air with integral blower, air intake from sides and rear, exhaust al rear
RF Connectors	Type N (temale), Front panel (rear panel, Option J)
Prime Power	115 Vac, 210%, 50/60 Hz, single phase; (100 and 230 Vac, Options Q and K)
Power Consumption	400 Watts
Dimensions (WxHxD)	19 x 3.5 x 19.25 inches; 480 x 89 x 487 millimeters
Weight	35 bs./15.9 kg. (max.)

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OPTIONS

- A Input Isolator: Inserted between the input and the TWT. Input VSWR is reduced to less than 1.5:1
- Input RF Attenuator: 20 dB continuous variation of RF gain (except for L-Band which is 10 dB). This attenuator is connected after the input isolator.
- C Harmonic Filter: Inserted after the output isolator. The amount of filtering depends upon the harmonicfrequency relative to the upper band edge.
- Output Isolator: Inserted immediately following the TWT lo isolate il from load mismatches. The result is improved gain flatness vs. frequency and protection of the TWT. The output VSWR is reduced to 1.5:1 typically. Max. is 2.0:1
- E RF Qutput Sample Port: 40 dB directional coupler added at the output following the output isolator. It is brought to the front panel via a Type N connector.

Frequency Attenuation Relative lo upper band edge	Attenuation (Typical)
0.95	0.25 dB to 2 GHz
	0.35 dB to 18 GHz
1.00	0.25 dB to 2 GHz 0.35 dB to 8 GHz 0.45 dB to 18 GHz
1.05	3dB
1.20	30dB
1.35 and above	60 dB

- **F** Chassis Slides
- Remote Control; Rear Panel connector providing remote control of Mains Power ON/OFF, High Voltage ON/OFF — FAULT RESET and External Interlock.
 Mains Power ON requires +12 volts at 30 mA from an external power supply. High Voltage ON/OFF is a contact closure to ground. External Interlock is a contact closure which must be closed for the amplifier to operate.
 All Front Panel status indications are brought to this connector via open collector transistor oulpuls to ground raled at 14 Volts max. collector to emitier at 30 mA max.
- H Elapsed Time Meter

J Rear RF Connectors

K 230 Vac Mains Prime Power

Solid State Input Pre-Amplifier: Inserted between the RF attenuator and the TWT. Raises the overall gain so that at least 0 dBm will produce rated power output.

- Q 100 Vac Mains Prime Power
- U SMA Adapters
 - **Note 1** The incorporation of all microwave options reduces the overall gain of the amplifier by the sum total of the insertion losses. (See Table 1.)
- Note 2 The incorporation of all microwave options at the outpul reduces the maximum power delivered to the output connector by the sum total of the insertion losses. (See Table 1.)

TABLE 1

Insertion Loss (dB) for Various Microwave Option Configurations

Frequency Loss Affec	Range (GHz) ts	1-2 Pwr Gain	2-4 Pwr Gain	4-8 Pwr Gain	8-12.4 Pwr Gain	12.4-18 Pwr Gain	8-18 Pwr Gain
Option	Description						
A	Input Isolator	— 0.6	— 0.6	— 0.6	— 0.6	— 0.6	0.6
В	RF Gain Adjust	— 1.0	— 1.0	— 1.0	— 1.0	— 1.0	— 1.5
С	Harmonic Filter	0.25 0.25	0.35 0.35	0.45 0.45	0.45 0.45	0.45 0.45	0.45 0.45
D	Output Isolator	0.6 0.6	0.6 0.6	0.6 0.6	0.6 0.6	0.6 0.6	0.6 0.6
E	RF Sample Port	0.3 0.4	0.4 0.4	0.4 0.4	0.4 0.4	0.6 0.6	0.5 0.5
J	Rear Connecter	0.15 —	0.25 0.4	0.4 0.4	0.5 0.5	0.6 0.6	0.6 0.6

Note 2

2 Note: Characteristics and operating values are based on performance tests. These figures may change without notice as a result of additional data or product refinement. Please contact CPI before using this information for system design.

BLOCK DIAGRAM



OUTLINE DRAWING





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